NXP Semiconductors User's Guide

# i.MX 8MDQLQ Hardware Developer's Guide

# 1. Overview

This document aims to help hardware engineers design and test the i.MX 8MDQLQ series processor. It gives examples on board layout, design checklists to ensure first-pass success, and solutions to avoid board bring-up problems.

Engineers should understand board layouts and board hardware terminology.

This guide is released with relevant device-specific hardware documentation such as datasheets, reference manuals, and application notes. All these documents are available on <a href="https://www.nxp.com/i.MX8M">www.nxp.com/i.MX8M</a>.

### 1.1. Device supported

This Hardware Developer's Guide supports the i.MX 8MDQLQ (17 x 17 mm package).

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### 1.2. Essential references

This guide is supplementary to the i.MX 8DQLQ series chip reference manuals and data sheets. For reflow profile and thermal limits during soldering, see *General Soldering Temperature Process Guidelines* (document *AN3300*). These documents are available on <u>www.nxp.com/i.MX8M</u>.

# **1.3. Supplementary references**

### 1.3.1. General information

The following documents introduces the Arm<sup>®</sup> processor architecture and computer architecture.

- For information about the Arm Cortex<sup>®</sup>-A35 processor, see: <u>https://www.arm.com/products/processors/cortex-a/cortex-a35-processor.php</u>
- For information about the Arm Cortex-A53 processor, see: <u>https://www.arm.com/products/processors/cortex-a/cortex-a53-processor.php</u>
- For information about the Arm Cortex-A72 processor, see: https://www.arm.com/products/processors/cortex-a/cortex-a72-processor.php
- For information about the Arm Cortex-M4F processor, see: <u>https://www.arm.com/products/processors/cortex-m/cortex-m4-processor.php</u>
- <u>Computer Architecture: A Quantitative Approach</u> (Fourth Edition) by John L. Hennessy and David A. Patterson
- <u>Computer Organization and Design: The Hardware/Software Interface</u> (Second Edition), by David A. Patterson and John L. Hennessy

The following documentation introduces the high-speed board design:

- <u>Right the First Time- A Practical Handbook on High Speed PCB and System Design Volumes I</u> <u>& II</u> - Lee W. Ritchey (Speeding Edge) - ISBN 0-9741936- 0-72
- <u>Signal and Power Integrity Simplified</u> (2nd Edition) Eric Bogatin (Prentice Hall)- ISBN 0-13-703502-0
- <u>High Speed Digital Design- A Handbook of Black Magic</u> Howard W. Johnson & Martin Graham (Prentice Hall) ISBN 0-13-395724-1
- <u>High Speed Signal Propagation- Advanced Black Magic</u> Howard W. Johnson & Martin Graham (Prentice Hall) ISBN 0-13-084408-X
- <u>High Speed Digital System Design- A handbook of Interconnect Theory and Practice</u> Hall, Hall and McCall (Wiley Interscience 2000) ISBN 0-36090-2
- <u>Signal Integrity Issues and Printed Circuit Design</u> Doug Brooks (Prentice Hall) ISBN 0-13-141884-X
- <u>PCB Design for Real-World EMI Control</u> Bruce R. Archambeault (Kluwer Academic Publishers Group) ISBN 1-4020-7130-2
- <u>Digital Design for Interference Specifications</u> A Practical Handbook for EMI Suppression -David L. Terrell & R. Kenneth Keenan (Newnes Publishing) ISBN 0-7506-7282-X

- <u>Electromagnetic Compatibility Engineering</u> Henry Ott (1st Edition John Wiley and Sons) -ISBN 0-471-85068-3
- <u>Introduction to Electromagnetic Compatibility</u> Clayton R. Paul (John Wiley and Sons) ISBN 978-0-470-18930-6
- <u>Grounding & Shielding Techniques</u> Ralph Morrison (5th Edition John Wiley & Sons) ISBN 0-471-24518-6
- EMC for Product Engineers Tim Williams (Newnes Publishing) ISBN 0-7506- 2466-3

### 1.4. Related documentation

Additional literature will be published when new NXP products become available.

For the list of current documents, see www.nxp.com/i.MX8M.

### 1.5. Conventions

 Table 1 lists the notational conventions used in this document.

Conventions	Description	
Courier	Used to indicate commands, command parameters, code examples, and file and directory names.	
Italics	Used to indicates command or function parameters.	
Bold	Function names are written in bold.	
cleared/set	When a bit takes the value zero, it means to be cleared; when it takes a value of one, it means to be set.	
mnemonics	Instruction mnemonics are shown in lowercase bold. Book titles in text are set in italics.	
sig_name	Internal signals are written in all lowercase.	
nnnn nnnnh	Denotes hexadecimal number	
0b	Denotes binary number	
rA, rB	Instruction syntax used to identify a source GPR	
rD	Instruction syntax used to identify a destination GPR	
REG[FIELD]	Abbreviations for registers are shown in uppercase. Specific bits, fields, or ranges appear in brackets.	
	For example, MSR[LE] refers to the little-endian mode enable bit in the machine state register.	
x	An italicized x indicates an alphanumeric variable.	
<i>n</i> , <i>m</i>	An italicized <i>n</i> indicates a numeric variable.	

Table 1.	Conventions used in the document
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In this guide, notation for all logical, bit-wise, arithmetic, comparison, and assignment operations follow C Language conventions.

# 1.6. Acronyms and abbreviations

Table 2 defines the acronyms and abbreviations used in this document.

Table 2.	Definitions a	nd acronyms
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Acronym	Definition	
ARM™	Advanced RISC Machines processor architecture	
BGA	Ball Grid Array package	
BOM	Bill of Materials	
BSDL	Boundary Scan Description Language	
CAN	Flexible Controller Area Network peripheral	
CCM	Clock Controller Module	
CSI	MIPI Camera Serial Interface	
DDR	Dual Data Rate DRAM	
DDR3L	Low voltage DDR3 DRAM	
DDR4	DDR4 DRAM	
DDRC	DDR Controller	
DFP	Downstream Facing Port (USB Type-C)	
DRP	Dual Role Port (USB Type-C)	
ECSPI	Enhanced Configurable SPI peripheral	
EIM	External Interface Module	
ENET	10/100/1000 Mbps Ethernet MAC peripheral	
EPIT	Enhanced Periodic Interrupt Timer peripheral	
ESR	Equivalent Series Resistance	
GND	Ground	
GPC	General Power Controller	
GPIO	General Purpose Input/Output	
HDCP	High-bandwidth Digital Content Protection	
I <sup>2</sup> C	Inter-integrated Circuit interface	
IBIS	Input output Buffer Information Specification	
IOMUX	i.MX 8MDQLQ chip-level I/O multiplexing	
JTAG	Joint Test Action Group	
KPP	Keypad Port Peripheral	
LDB	LVDS Display Bridge	
LDO	Low Drop-Out regulator	
LPCG	Low Power Clock Gating	
LPDDR4	Low Power DDR4 DRAM	
LVDS	Low-Voltage Differential Signaling	
MLB	Media Local Bus	
ODT	On-Die Termination	
OTP	One-Time Programmable	
PCB	Printed Circuit Board	
PCle	PCI Express	
PCISig	Peripheral Component Interconnect Special Interest Group	
PDN	Power Distribution Network	
PMIC	Power Management Integrated Circuit	
POR	Power-On Reset	
PTH	Plated Through Hole PCB (i.e. no microvias)	
RGMII	Reduced Gigabit Media Independent Interface (Ethernet)	
RMII	Reduced Media Independent Interface (Ethernet)	
ROM	Read-Only Memory	

# 2. i.MX 8MDQLQ design checklist

This document provides a design checklist for the i.MX 8MDQLQ ( $17 \times 17$  mm package) processor. The design checklist tables recommend optimal design and provide explanations to help users understand better. All supplemental tables referenced by the checklist appear in sections following the design checklist tables.

# 2.1. Design checklist table

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Connect the ZQ ball on the processor (ball AA13) to individual 240 Ω, 1 % resistors to GND.</li> </ol>	This is a reference used during DRAM output buffer driver calibration.
	<ol> <li>The ZQ0 and ZQ1 balls on LPDDR4 device should be connected through 240 Ω, 1 % resistors to the LPDDR4 VDDQ rail.</li> </ol>	-
	3. Place a 10 k $\Omega$ , 5 % resistor to ground on the DRAM reset signal.	This will ensure adherence to the JEDEC specification until the control is configured and starts driving the DDR.
	4. The VREF ball on the processor (ball AA14) should be connected to a voltage level of VDDQ/2.	In LPDDR4 mode, the VREF ball serve as ZQ calibration.
	<ol> <li>The processor balls AC12 and AE11 should be left unconnected. The ODT_CA balls on the LPDDR4 device should be connected directly or through a 10 kΩ to the LPDDR4 VDD2 rail.</li> </ol>	LPDDR4 ODT on the i.MX 8MDQLQ is command-based, making processor ODT_CA output balls unnecessary.
	6. The architecture for each chip inside the DRAM package must be x 16.	The processor does not support byte mode specified in JESD209-4B.
	7. The processor ball MTEST (ball AB14), MTEST1 (ball AC13), should be left unconnected.	These are observability ports for manufacturing and are not used otherwise.

Table 3. LPDDR4 recommendations (i.MX 8MDQLQ)

#### Table 4. DDR4/DDR3L recommendations (i.MX 8MDQLQ)

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Connect the ZQ ball on the processor (ball AA13) to individual 240 Ω, 1 % resistors to GND.</li> </ol>	This is a reference used during DRAM output buffer driver calibration.
	<ol> <li>The ZQ ball on each DDR4/DDR3L device should be connected through individual 240 Ω, 1 % resistors to GND.</li> </ol>	-
	3. The VREF ball on the processor (ball AA14) should be connected to a voltage level of VDDQ/2.	In DDR4 mode, the VREF ball serve as ZQ calibration.
	4. The processor ball MTEST (ball AB14), MTEST1 (ball AC13), should be left unconnected.	These are observability ports for manufacturing and are not used otherwise.

Check box	Recommendations	Explanation/Supplemental recommendations
	1. Verify the target I <sup>2</sup> C interface clock rates	The I <sup>2</sup> C bus can only be operated as fast as the slowest peripheral on the bus. If faster operation is required, move the slow devices to another I <sup>2</sup> C port.
	<ol> <li>Verify that there are no I<sup>2</sup>C address conflicts on any of the I<sup>2</sup>C buses utilized</li> </ol>	There are multiple $I^2C$ ports available on chip, so if a conflict exists, move one of the conflicting devices to a different $I^2C$ bus. If this isn't possible, use a $I^2C$ bus switch (NXP part number <u>PCA9646</u> ).
	<ol> <li>Do not place more than one set of pull-up resistors on the I<sup>2</sup>C lines.</li> </ol>	This could result in excessive loading and potential incorrect operation. Choose the pull-up value commensurate with the bus speed being utilized.
	<ol> <li>Ensure that the VCC rail powering the i.MX 8MDQLQ I<sup>2</sup>C interface balls matches the supply voltage used for the pull-up resistors and the slave I<sup>2</sup>C devices.</li> </ol>	Prevent device damage or incorrect operation due to voltage mismatch.

Table 5.	I <sup>2</sup> C recommendations
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#### Table 6. JTAG recommendations

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Do not use external pullup or pulldown resistors on JTAG_TDO.</li> </ol>	JTAG_TDO is configured with an on-chip keeper circuit and the floating condition is actively eliminated if an external pull resistor is not present.
	2. Follow the recommendations for external pull-up and pull-down resistors given in <b>Table 14</b> .	-
	<ol> <li>TEST_MODE (ball V7) should be connected to the ground.</li> </ol>	This ball is for factory use only.

#### Table 7. Reset and ON/OFF recommendations

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>The POR_B input must be asserted at power-up and remain asserted until the last power rail for devices required for system boot are at their working voltage. This functionality is controlled by the PMIC (PF4210) on EVK.</li> </ol>	POR_B is driven by the PMIC. If a reset button is used, it should be connected to the enable pin of the PMIC and/or other power supply chips instead of directly connected to POR_B pin of the CPU. When POR_B is asserted (low) on the i.MX 8MDQLQ, the output PMIC_ON_REQ remains asserted (high).
	<ol> <li>For portable applications, the ON_OFF_BUTTON input may be connected to an ON/OFF SPST push- button switch to ground. If the On-chip debouncing is provided, this input has an on-chip pullup. Otherwise, the ON_OFF_BUTTON should not be connected.</li> </ol>	A brief connection to GND in OFF mode causes the internal power management state machine to change state to ON. In ON mode, a brief connection to GND generates an interrupt (intended to initiate a software-controllable power-down). The connection to GND for approximate 5 second or more causes a forced OFF.

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Comply with the power-up sequence guidelines as described in the datasheet to guarantee reliable operations of the device.</li> </ol>	<ul> <li>Any deviation from these sequences may result in the following situations:</li> <li>Excessive current during power-up phase</li> <li>Prevention of the device from booting</li> <li>Irreversible damage to the processor (worst case)</li> </ul>
	2. Maximum ripple voltage requirements	Common requirement for ripple noise peak-to- peak value should be less than 5 % of the supply voltage nominal value.

Table 8. i.MX 8MDQLQ power/decoupling recommendations

#### Table 9. Decoupling capacity recommendations (i.MX 8MDQLQ)

Checkbox	Supply	4.7 nF	0.01 μF	0.1 μF	1 µF	2.2 μF	22 µF	Notes
	VDD_DRAM	11	2		4	-	3	Location of these capacitors is critical for effective decoupling. See layout of EVK for the optimum location of these decoupling capacitors.
	NVCC_DRAM	-	-	-	18	-	3	-
	VDD_ARM	-	-	-	9	-	3	-
	VDD_GPU	-	-	-	7	-	3	-
	VDD_VPU	-	-	-	4	-	6	-
	VDD_SOC	-	-	-	10	-	3	-
	VDD_SNVS	-	-	1	-	-	-	-
	NVCC_SNVS	-	-	-	1	-	-	-
	VDDA_0P9	-	-	-	1	-	-	This rail should be sourced from the VDD_SOC rail through a 240 $\Omega$ ferrite bead.
	VDDA_DRAM, VDDA_1P8_XXX	-	-	6	-	-	1	-
	NVCC_JTAG, NVCC_NAND, NVCC_SAI1, NVCC_SAI2, NVCC_SAI3, NVCC_SAI5, NVCC_GPIO1, NVCC_I2C, NVCC_UART, NVCC_ECSPI	-	-	9	-	-	-	-
	NVCC_SD1	-	-	1	-	-	-	-
	NVCC_SD2	-	-	1	-	-	-	-
	NVCC_ENET	-	-	1	-	-	-	-
	USB1_VDD33, USB1_VPH, USB2_VDD33, USB2_VPH	-	-	2	-	1	-	-

		-						
Checkbox	Supply	4.7 nF	0.01 μF	0.1 μF	1 µF	2.2 µF	22 µF	Notes
	USB1_VPTX, USB1_VP, USB1_DVDD, USB2_VPTX, USB2_VP, USB2_DVDD	-	-	2	-	1	-	-
	PCIE_VPH	-	-	1	-	1	-	-
	PCIE_VPTX, PCIE_VP	-	-	2	-	1	-	-
	HDMI_AVDDIO	-	-	1	-	1	-	-
	HDMI_AVDDCLK, HDMI_AVDDCORE	-	-	2	-	1	-	-
	MIPI_VDDHA	-	-	1	-	1	-	-
	MIPI_VDDA, MIPI_VDDPLL	-	-	3	-	1	-	-
	MIPI_VDD	-	-	2	-	-	-	MIPI_VDD and MIPI_VDDA can share the same source. MIPI_VDD should be isolated with a 120 Ω ferrite bead.
	Capacitor part number	er used on E	VK:					
	• 4.7 nF GRM033R61A472KA01D							
	• 0.01 uF GRM033R70J103KA01D							
	• 0.1 uF 0201X104K100CT							
	• 1 uF 02016D105MAT2A							
	• 2.2 uF C1005X5R1A225K							
	• 22 uF C1	608X5R1A	226M080AC					

Table 9. Decoupling capacity recommendations (i.MX 8MDQLQ)

Check box	Recommendations	Explanation/Supplemental recommendations
	1. Use an appropriate PCIe reference clock generator.	The NXP EVK board design uses an IDT 9FGV0241 device. However, NXP does not recommend one supplier over another, and does not suggest that this is the only clock generator supplier. The device used should support all the specs (jitter, accuracy, etc.). The internal PCIe reference clock is good for all standard PCIe applications. The clock may be connected to one or two external devices (depending on location). Use a buffer, distributor, or external clock reference for additional PCIe destinations.
	<ol> <li>The differential transmitters from the processor must be AC coupled. Use a 0.1 µF cap on both the PCIE_TXP and PCIE_TXN outputs</li> </ol>	PCIe specification compliance requires AC coupling at each transmitter. The receiver must be DC coupled.
	<ol> <li>The PCIEx_RESREF ball (ball G25 and C25) should be connected to the ground through a 200 Ω, 1 % resistor.</li> </ol>	-

Check box	Recommendations	Explanation/Supplemental recommendations
	1. Connect a 200 Ω, 1 % resistor to the ground on the USBx_RESREF ball (ball A11 and B11).	-
	<ol> <li>Route all USB differential signals with 90 Ω differential impedance.</li> </ol>	-
	<ol> <li>ESD protection should be implemented at the connector pins. Choose a low capacitance device recommended for high-speed interfaces.</li> </ol>	This will prevent potential damages to board components from ESD.

#### Table 11. USB recommendations

#### Table 12. HDMI recommendations

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Connect a 499 Ω, 1 % resistor to ground on the HDMI_REXT ball (ball P1).</li> </ol>	-
	<ol> <li>Route all HDMI differential pairs with 100 Ω differential impedance.</li> </ol>	-

#### Table 13. Oscillator/Crystal recommendations

Check box	Recommendations	Explanation/Supplemental recommendations
	<ol> <li>Connect a 25 MHz crystal between XTALI_25M and XTALO_25 M (balls U24 and U25).</li> </ol>	This crystal should have ESR not greater than $50 \Omega$ , and be rated for a drive level of at least $200 \mu$ W. Follow the manufacturer's recommendation for loading capacitance. Use short traces between the crystal and the processor, with a ground plane under the crystal, load capacitors, and associated traces.
	2. Connect a 27 MHz crystal between XTALI_27M and XTALO_27M (balls V24 and V25).	This crystal should have ESR not greater than 50 $\Omega$ , and be rated for a drive level of at least 200 $\mu$ W. Follow the manufacturer's recommendation for loading capacitance. Use short traces between the crystal and the processor, with a ground plane under the crystal, load capacitors, and associated traces.
	<ol> <li>The i.MX 8MDQLQ 32.768 kHz needs to be driven with an external clock (oscillator) into the RTC input (ball V22).</li> </ol>	The voltage level of this driving clock should not exceed the voltage of the NVCC_SNVS rail and the frequency should be less than 100 kHz. Do not exceed NVCC_SNVS, or the damage/malfunction may occur. The RTC signal should not be driven if the NVCC_SNVS supply is OFF. It can lead to damage or malfunction. For RTC $V_{IL}$ and $V_{IH}$ voltage levels, see the latest i.MX 8MDQLQ datasheet available at <u>www.nxp.com/i.MX8M</u> .

# 2.2. JTAG signal termination

Table 14 is a JTAG termination chart showing what terminations should be placed on PCB designs.

JTAG signal	I/O type	External termination	Comments
JTAG_TCK	Input	10 kΩ pull-down	
JTAG_TMS	Input	None	Internal pulled up to NVCC_JTAG, no external termination required
JTAG_TDI	Input	None	Internal pulled up to NVCC_JTAG, no external termination required
JTAG_TDO	3-state output	None	
JTAG_TRSTB	Input	None	No connection from JTAG to processor, internal pulled up to NVCC_JTAG

Table 14. Recommended JTAG board terminations

# 3. i.MX 8MDQLQ layout/routing recommendations

# 3.1. Introduction

This chapter introduces how to assist design engineers with the layout of an i.MX 8MDQLQ-based system.

# 3.2. Basic design recommendations

When using the Allegro design tool, the schematic symbol & PCB footprint created by NXP is recommended. When not using the Allegro tool, use the Allegro footprint export feature (supported by many tools). If the export is not possible, create the footprint per the package dimensions outlined in the product data sheet.

Native Allegro layout and gerber files are available on <u>www.nxp.com/i.MX8M</u>.

## 3.2.1. Placing decoupling capacitors

Place small decoupling and larger bulk capacitors on the bottom side of the PCB.

The 0201 or 0402 decoupling and 0603 or larger bulk capacitors should be mounted as close as possible to the power vias. The distance should be less than 50 mils. Additional bulk capacitors can be placed near the edge of the BGA via array. Placing the decoupling capacitors close to the power balls is critical to minimize inductance and ensure high-speed transient current required by the processor. See the i.MX 8MDQLQ EVK layouts for examples of the desired decoupling capacitor placement.

The following list introduces how to choose correct decoupling scheme:

- Place the largest capacitance in the smallest package that budget and manufacturing can support.
- For high speed bypassing, select the required capacitance with the smallest package (for example, 0.1  $\mu$ F, 0.22  $\mu$ F, 1.0  $\mu$ F, or even 2.2  $\mu$ F in a 0201 package size).

- Minimize trace length (inductance) to small caps.
- Series inductance cancels out capacitance.
- Tie caps to GND plane directly with a via.
- Place capacitors close to the power ball of the associated package from the schematic.
- A preferred BGA power decoupling design is available on the EVK board design available on <u>www.nxp.com/i.MX8M</u>. Customers should use the NXP design strategy for power and decoupling.

# 3.3. Stack-up recommendations

### 3.3.1. Stack-up recommendation (i.MX 8MDQLQ)

Due to the number of balls on the i.MX 8MDQLQ processor in the 17 mm  $\times$  17 mm package, a minimum 8-layer PCB stackup is recommended. Of the 8-layers on the PCB, a sufficient number of layers need to be dedicated to power on routing to meet the IR drop target of 1 % for the i.MX 8MDQLQ CPU power rails.

The constraints for the trace width will depend on such factors as the board stackup and associated dielectric and copper thickness, required impedance, and required current (for power traces). The stackup also determines the constraints for routing and spacing. Consider the following requirements when designing the stackup and selecting board material:

- Board stack-up is critical for high-speed signal quality.
- Preplanning impedance of critical traces is required.
- High-speed signals must have reference planes on adjacent layers to minimize cross-talk.
- PCB material: the material used on EVK is TU768.

# 3.4. DDR design recommendations

### 3.4.1. DDR connection information

The i.MX 8MDQLQ processor can be used with LPDDR4, DDR4 or DDR3L memory. Since these memory types have different I/O signals, there are 37 generically-named functional balls, depending on the type of memory used. See **Table 15** for the connectivity of these generic balls for DDR3L, LPDDR4 and DDR4. The schematic symbol created by NXP already replaced these generic names with DDR function.

Ball name	Ball #	LPDD4 function	DDR4 function	DDR3L function
DRAM_AC00	AC16	CKE0_A	CKE0	CKE0
DRAM_AC01	AE17	CKE1_A	CKE1	CKE1
DRAM_AC02	AE18	CS0_A	CS0_n	CS0#
DRAM_AC03	AC18	CS1_A	CO	-
DRAM_AC04	AD14	CK_t_A	BG0	BA2
DRAM_AC05	AE14	CK_c_A	BG1	A14

Table 15. DDR3L/LPDDR4/DDR4 connectivity
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Ball name	Ball #	LPDD4 function	DDR4 function	DDR3L function
DRAM_AC06	AE13	-	ACT_n	A15
DRAM_AC07	AB15	-	A9	A9
DRAM_AC08	AD17	CA0_A	A12	A12/BC#
DRAM_AC09	AE16	CA1_A	A11	A11
DRAM_AC10	AD20	CA2_A	A7	A7
DRAM_AC11	AE20	CA3_A	A8	A8
DRAM_AC12	AD19	CA4_A	A6	A6
DRAM_AC13	AE19	CA5_A	A5	A5
DRAM_AC14	AB16	-	A4	A4
DRAM_AC15	AC15	-	A3	A3
DRAM_AC16	AE15	-	CK_t_A	CK_A
DRAM_AC17	AD15	-	CK_c_A	CK#_A
DRAM_AC19	AB14	MTEST	MTEST	MTEST
DRAM_AC20	AD10	CKE0_B	CK_t_B	CK_B
DRAM_AC21	AE10	CKE1_B	CK_c_B	CK#_B
DRAM_AC22	AD8	CS1_B	-	-
DRAM_AC23	AC9	CS0_B	-	-
DRAM_AC24	AD12	CK_t_B	A2	A2
DRAM_AC25	AE12	CK_c_B	A1	A1
DRAM_AC26	AB12	-	BA1	BA1
DRAM_AC27	AA12	-	PARITY	-
DRAM_AC28	AC7	CA2_B	A13	A13
DRAM_AC29	AE7	CA3_B	BA0	BA0
DRAM_AC30	AE6	CA4_B	A10 / AP	A10 / AP
DRAM_AC31	AD6	CA5_B	A0	A0
DRAM_AC32	AE8	CA0_B	C2	-
DRAM_AC33	AE9	CA1_B	CAS_n / A15	CAS#
DRAM_AC34	AC10	-	WE_n / A14	WE#
DRAM_AC35	AB10	-	RAS_n / A16	RAS#
DRAM_AC36	AC12	-	ODT0	ODT0
DRAM_AC37	AE11	-	ODT1	ODT1
DRAM_AC38	AC11	-	CS1_n	CS1#

#### Table 15. DDR3L/LPDDR4/DDR4 connectivity

### 3.4.2. LPDDR4-3200 design recommendations

The following list details some generic guidelines that should be adhered to when implementing an i.MX 8MDQLQ design using LPDDR4.

- 1. It is expected that the layout engineer and design team already has experience and training with DDR designs at speeds of 1.6 GHz/3200 MT/s.
- 2. Refer to solid GND plane only for all the high-speed signal traces. If referring to both GND and NVCC\_DRAM (VDDQ) plane, make sure the dielectric thickness between trace and NVCC\_DRAM plane is larger than that between trace and GND plane. Do not refer to other power planes.
- 3. The impedance of DQ and DMI signal traces should be controlled to 42 ohm instead of 50 ohm to maximize the timing margin at 3200 MT/s.

- 4. The DQ/DMI/DQS signals must be routed in inner layers as stripline or embedded microstrip and follow 3W rule(center to center) to minimize trace crosstalk.
- 5. At a speed of 3200 MT/s, signal vias can be a significant source of crosstalk. If not properly designed, it can introduce crosstalk larger than that from the trace. To minimize via crosstalk, make sure the total number of vias to be two or less on each point-to-point single-ended/differential trace. Place at least one ground stitching via within 40 mils of signal via when switching reference planes to provide continuous return path and reduce crosstalk. If it is not possible to place enough ground stitching vias due to space limitation, try to make the length that the signal actually travels on the via as short as possible, as illustrated in **Figure 1**.

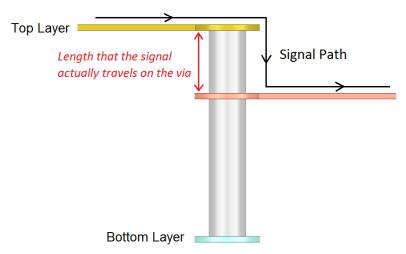


Figure 1. Length that the signal actually travels on the Via

- 6. Route the CLK signal on top layer with no via transition and keep over than 5 W spacing from other signals.
- 7. DQS and DMI with the same slice should have the same number of vias/layer changes.
- 8. Use time delay instead of length when performing the delay matching. The delay matching includes the PCB trace delay and the IC package delay. Incorporate the package pin delay into the CAD tool's constraint manager.
- 9. Include the delay of vias when performing delay matching. This can be realized in Allegro tool by enabling the **Z** Axis Delay in "Setup -> Constraints -> Modes".
- 10. Byte swapping within each 16-bit channel is OK. Bit swapping within each slice/byte lane is OK.
- 11. Bit swapping of Command/Address (CA[5:0]) signals is **NOT** allowed.
- 12. For an i.MX 8MDQLQ design, DRAM\_AC14 and DRAM\_AC34 on the processor must be left unconnected if using LPDDR4. The ODT\_CA balls on the LPDDR4 devices should be connected directly or through a resistor to the VDD2 supply.
- 13. In general, the 200-ball LPDDR4 package should be placed 100 mils from the i.MX 8MDQLQ.
- 14. Enable the DBI (data bus inversion) feature. It can help reduce both power consumption and power noise.

### 3.4.2.1. i.MX 8MDQLQ LPDDR4-3200 routing recommendations

LPDDR4-3200 needs to be routed with signal fly times matched shown in **Table 16**. The delay of the via transitions needs to be included in the overall calculation. This can be realized in Allegro tool by enabling the **Z** Axis Delay in "Setup - Constraints - Modes".

An example of the delay match calculation has been shown for the i.MX 8MDQLQ EVK board design in **Table 17** and **Table 18**. This analysis was done for the LPDDR4-3200 implementation using the i.MX 8MDQLQ. In **Table 17**, the **PCB Delay** column was obtained directly from the Allegro PCB file, and the **Pkg Delay** column is the package delay obtained from **Table 24**.

Table 10: Infill Gill QLQ III DDA(+ 5200 Fouring recommendations						
LPDDR4-3200						
LPDDR4 signal (each	Group	PCB + package prop delay				
16-bit channel)		Min	Мах	Considerations		
CK_t/CK_c	Clock	Short as possible	175 ps	Match the true/complement signals within 1 ps.		
CA[5:0] CS[1:0] CKE[1:0]	Address/ Command/ Control	CK_t - 25 ps	CK_t + 25 ps			
DQS0_t/DQS0_c	Byte 0 - DQS	CK_t - 85 ps	CK_t + 85 ps			
DM0 DQ[7:0]	Byte 0 - Data	DQS0_t -10 ps	DQS0_t +10 ps			
DQS1_t/DQS1_c	Byte 1 - DQS	CK_t - 85 ps	CK_t + 85 ps	Match the		
DM1 DQ[15:8]	Byte 1 - Data	DQS1_t -10 ps	DQS1_t +10 ps	true/complement signals of DQS within 1 ps.		

#### NXP recommends that users simulate their LPDDR4 implementation before fabricating PCBs. Table 16. i.MX 8MDQLQ LPDDR4-3200 routing recommendations

Table 17. LPDDR4 delay matching example (CA/CTL signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
	106.6	42.7	Routed on top layer, no via
DRAM_CK_T_A	149	9.3	Total Net Delay
DRAM_CK_C_A	107.1	41.5	Routed on top layer, no via
	148	3.6	Total Net Delay
DRAM CA0 A	105.0	49.8	Vias are L1-> L8->L1
DRAIM_CAU_A	154	4.8	Total Net Delay
	85.1	73.5	Vias are L1-> L8->L1
DRAM_CA1_A	158	3.6	Total Net Delay
	106.6	51.2	Vias are L1-> L8->L1
DRAM_CA2_A	157	7.8	Total Net Delay
	106.2	52.6	Vias are L1-> L8->L1
DRAM_CA3_A	158	3.8	Total Net Delay
	111.8	58.6	Vias are L1-> L8->L1
DRAM_CA4_A	170	).4	Total Net Delay
	105.7	56.2	Vias are L1-> L8->L1
DRAM_CA5_A	161	1.9	Total Net Delay
DRAM CCO A	106.6	51.0	Vias are L1-> L8->L1
DRAM_nCS0_A	157	7.6	Total Net Delay
DRAM pCS1 A	108.1	47.8	Vias are L1-> L8->L1
DRAM_nCS1_A	155	5.9	Total Net Delay
DRAM_CKE0_A	121.1	36.5	Vias are L1-> L8->L1

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
	157.6		Total Net Delay
DRAM CKE1 A 106.1		47.4	Vias are L1-> L8->L1
DRAW_CKET_A	M_CKE1_A 153		Total Net Delay

Table 17. LPDDR4 delay matching	example (CA/CTL signals)
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#### Table 18. LPDDR4 length matching example (byte lane 1 signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
DRAM SDOS1 T A	180.1	45.2	Vias are L1-> L4->L1
DRAM_SDQS1_T_A	225	5.3	Total Net Delay
DRAM_SDQS1_C_A	179.5	45.3	Vias are L1-> L4->L1
DRAW_SDQS1_C_A	224	.8	Total Net Delay
DRAM_DMI1_A	180.2	43.4	Vias are L1-> L4->L1
DRAM_DIMIT_A	223	3.6	Total Net Delay
DRAM DATA8 A	179.1	44.2	Vias are L1-> L4->L1
	223	3.3	Total Net Delay
DRAM_DATA9_A	182.7	46.5	Vias are L1-> L4->L1
DIVANI_DATA9_A	229	0.2	Total Net Delay
DRAM_DATA10_A	175.5	53.8	Vias are L1-> L4->L1
DIVAM_DATATO_A	229	0.3	Total Net Delay
DRAM_DATA11_A	185.9	43.5	Vias are L1-> L4->L1
DRAM_DATATI_A	229	).4	Total Net Delay
DRAM DATA12 A	179.1	44.9	Vias are L1-> L4->L1
DRAM_DATATZ_A	224	.0	Total Net Delay
DRAM DATA13 A	182.0	45.0	Vias are L1-> L4->L1
DRAM_DATATS_A	227	.0	Total Net Delay
DRAM DATA14 A	188.0	35.3	Vias are L1-> L4->L1
DIXAW_DATAT4_A	223	3.3	Total Net Delay
DRAM DATA15 A	184.3	40.4	Vias are L1-> L4->L1
DRAW_DATATS_A	224	.7	Total Net Delay

#### 3.4.2.2. LPDDR4-3200 routing example (i.MX 8MDQLQ)

**Figure 2** to **Figure 5** show the placement and routing of the LPDDR4 signals on the i.MX 8MDQLQ EVK board. The CLK signals are routed on top layer with no via to achieve the best signal quality. Data byte lane 1 signals are routed on layer 4 to make the length that the signal actually travels on the via as short as possible, as limited number of GND vias can be placed near these signal vias. Data byte lane 0 signals are routed on layer 6. CA/CTL signals are routed on layer 8 as their data rate is only half of the data signals, and CA/CTL has more tolerance for crosstalk.

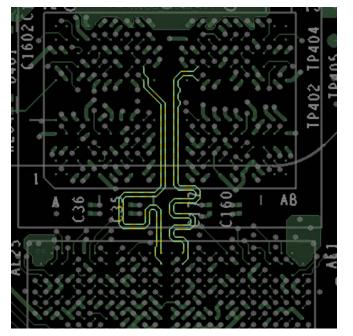


Figure 2. i.MX 8MDQLQ EVK board LPDDR4 routing (top layer)

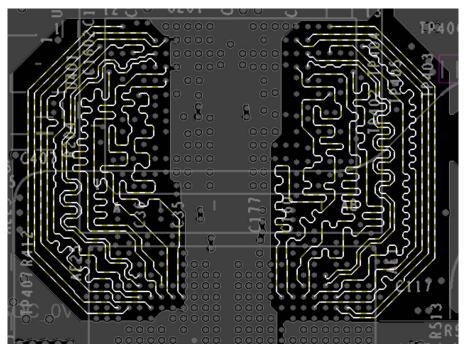


Figure 3. i.MX 8MDQLQ EVK board LPDDR4 routing (Layer 4)

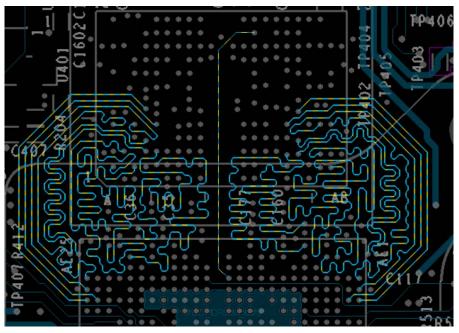


Figure 4. i.MX 8MDQLQ EVK board LPDDR4 routing (Layer 6)

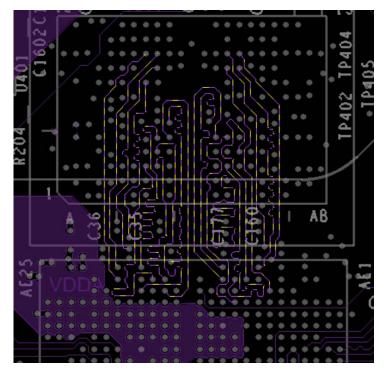


Figure 5. i.MX 8MDQLQ EVK board LPDDR4 routing (Layer 8)

### 3.4.2.3. LPDDR4-3200 SI simulation guide

The simulation architecture includes the DDR controller (i.e. the i.MX 8MDQLQ processor), the PCB and the LPDDR4 device. The IBIS model for the i.MX 8MDQLQ processor is available from NXP. The LPDDR4 device IBIS model must be obtained from the memory vendor.

This section introduces how to check SI performance of the layout for an LPDDR4-3200 design using the i.MX 8MDQLQ.

- Firstly, perform S-parameter extraction:
  - It requires a 2.5D full-wave extraction tool, such as PowerSI from Cadence.
  - Set the extraction bandwidth to 20 GHz.
  - Port reference impedance: 50  $\Omega$  for signal ports, and 0.1  $\Omega$  for power ports.
  - Coupled mode: Set the rise time to 20 ps and coupling coefficient to 1 %.
- Secondly, perform time domain simulation:
  - Stimulus pattern: 500-bit random code and different pattern for each signal within the same byte.
  - Ideal power.
  - Probe at the die.
  - Simulation at slow corner (worst case).
  - Eye waveform triggered by aligning with the timing reference (DQS/CLK).

#### 3.4.2.4. Eye width requirement

The simulated worst eye width should meet following requirements:

- DQ Write: Eye width  $@V_{REF} \pm 70 \text{mV}$  should be over 221 ps.
- CA/CTL: Eye width  $@V_{REF} \pm 77.5 \text{mV}$  should be over 340 ps.

Figure 6 shows an example of simulated eye width of DQ write.

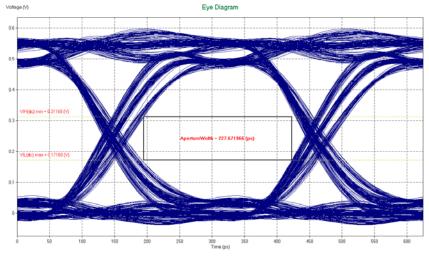


Figure 6. Example of simulated eye width

### 3.4.3. i.MX 8MDQLQ DDR4-2400/DDR3L-1600 design recommendations

The following list details some generic guidelines that should be adhered to when implementing an i.MX 8MDQLQ design using DDR4/DDR3L.

1. Use a T PCB routing topology for a 2-rank system. Mount a rank of SDRAM on both top and bottom of the board, mirroring in a clamshell design for highest performance.

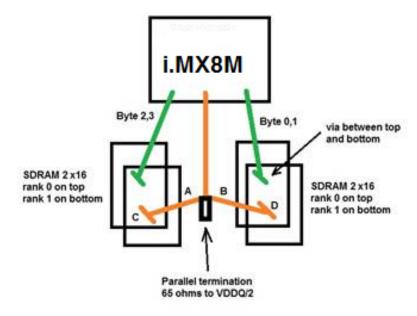


Figure 7. PCB routing topology for a 2-rank system

- 2. As illustrated in **Figure 7**, for data bytes, route straight from SOC to the SDRAM devices and via up and down with minimal stubs. For address/command signals, it is a T structure with branch to the SDRAM devices and via up and down with minimal stubs. And add a parallel termination (about 65 ohm to VDDQ/2 or VTT) at the branch point of the T.
- 3. The branch and stubs to the SDRAM pins must be the same length on both sides of the branch point (A+C=B+D); otherwise, the signal will show significant distortion. Also try to minimize length of branch as it is un-terminated at the SDRAM devices.
- 4. The impedance of DQ& DMI & the trunk of address/command signal traces should be controlled to 40 ohm instead of 50 ohm to maximize the timing margin.
- 5. All data signals within a byte lane should have the same number of vias/layer changes.
- 6. All the high-speed signal traces must be referred to solid GND or NVCC\_DRAM (VDDQ) plane. Do not refer to other power planes.
- 7. For DQ nets, bit swapping within each slice/byte lane is OK.
- 8. For Address nets, use address mirroring to minimize top to bottom stubs. i.MX 8MDQLQ supports address mirroring but the wiring from i.MX 8MDQLQ to the two DRAM ranks must conform to **Table 19** and **Table 20**, for DDR4 and DDR3L respectively.

DDR4-2400			
i.MX 8MDQLQ pin	DRAI	M pin	
	Rank 0	Rank 1	
A3	A3	A4	
A4	A4	A3	
A5	A5	A6	
A6	A6	A5	
A7	Α7	A8	
A8	A8	A7	
A11	A11	A13	
A13	A13	A11	
BA0	BA0	BA1	
BA1	BA1	BA0	

#### Table 19. Wiring definition for DDR4 address mirroring

#### Table 20. Wiring definition for DDR3L address mirroring

DDR3L-1600			
i.MX 8MDQLQ pin	DRAI	M pin	
	Rank 0	Rank 1	
A3	A3	A4	
A4	A4	A3	
A5	A5	A6	
A6	A6	A5	
A7	A7	A8	
A8	A8	A7	
BA0	BA0	BA1	
BA1	BA1	BA0	

- 9. The DQ/DMI/DQS signal must follow 3 W rule (center to center) to minimize trace crosstalk.
- 10. Place at least one ground stitching via within 40 mils of signal via when switching reference planes to provide continuous return path and reduce crosstalk. If it is not possible to place enough ground stitching vias due to space limitation, try to make the length that the signal actually travels on the via as short as possible, as illustrated in **Figure 8**.

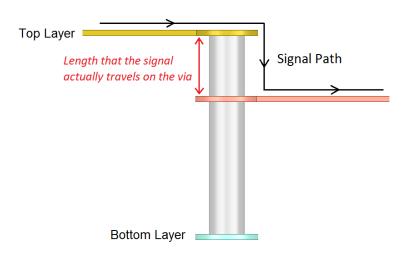


Figure 8. Length that the signal actually travels on the Via

- 11. Use time delay instead of length when performing the delay matching. The delay matching includes the PCB trace delay and the IC package delays. Incorporate the package pin delay into the CAD tool's constraint manager.
- 12. Consider the delay of vias when performing delay matching. This can be realized in Allegro tool by enabling **Z** Axis Delay in "Setup Constraints Modes".

### 3.4.3.1. i.MX 8MDQLQ DDR4-2400 / DDR3L-1600 routing recommendations

DDR4-2400/DDR3L-1600 needs to be routed with signal fly times matched as shown in Table 21.

The delay of the via transitions needs to be included in the overall calculation. This can be realized in Allegro tool by enabling "Z Axis Delay" in "Setup - Constraints - Modes".

An example of the delay match calculation has been shown for the i.MX 8MDQLQ validation board design in **Table 22** and **Table 23**. This analysis was done for the DDR4-2400 implementation using the i.MX 8MDQLQ. In **Table 22**, the **PCB Delay** column was obtained directly from the Allegro PCB file, and the **Pkg Delay** column is the package delay obtained from **Table 24**.

NXP recommends that users simulate their DDR implementation before fabricating PCBs.

DDR4-2400/DDR3L-1600				
		PCB + packa	O	
DDR4/DDR3L signal	Group	Min	Max	- Considerations
CK_t/CK_c	Clock	Short as possible	400ps	Match the true/complement signals within 1 ps.
A[13:0] CS[1:0]/RAS/WE/CAS BA[1:0]/BG0	Address/ Command/ Control	CK_t - 25 ps	CK_t + 25 ps	-

Table 21. i.MX 8MDQLQ DDR4-2400/DDR3L-1600 routing recommendations	S
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CKE[1:0]/ ODT[1:0]				
DQS0_t/DQS0_c	Byte 0 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	Match the
DM0	Buto 0 Data	DOS0 t 10 pc		true/complement
DQ[7:0]	Byte 0 - Data	DQS0_t -10 ps	DQS0_t +10 ps	signals of DQS
DQS1_t/DQS1_c	Byte 1 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	within 1 ps.
DM1	Byte 1 - Data	DOS1 t 10 pc		
DQ[15:8]	Byle I - Dala	DQS1_t -10 ps	DQS1_t +10 ps	
DQS2_t/DQS2_c	Byte 2 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM2	Byte 2 - Data	DOS2 t 10 pc	DQS2 t+10 ps	
DQ[23:16]	Byle 2 - Dala	DQS2_t -10 ps	DQ32_(+10 ps	
DQS3_t/DQS3_c	Byte 3 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	]
DM3	Byte 3 Data	$DOS3 \pm 10$ pc	DQS3_t +10 ps	
DQ[31:24]	Byte 3 - Data	DQS3_t -10 ps	DQ35_(+10 ps	

#### Table 21. i.MX 8MDQLQ DDR4-2400/DDR3L-1600 routing recommendations

#### Table 22. DDR4 delay matching example (CA/CTL/CMD/CK signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
ACT_N	268.3	46.4	Vias are L1-> L8->L6->L8
U1.AE13: U4.L3	314	4.7	Total Net Delay
AO	271.8	62.6	Vias are L1-> L4->L6->L8
U1.AD6: U4.P3	334	4.4	Total Net Delay
A1	275.1	39.5	Vias are L1-> L8->L3->L8
U1.AE12: U4.P7	314		Total Net Delay
A2	276.6	41.3	Vias are L1-> L4->L6->L8
U1.AD12: U4.R3	31	7.9	Total Net Delay
A3	267.5	47.0	Vias are L1-> L4->L6->L8
U1.AC15: U4.N3	314	4.5	Total Net Delay
A4	280.0	44.4	Vias are L1-> L8->L6->L8
U1.AB16: U4.N7	324	4.4	Total Net Delay
A5	266.0	60.9	Vias are L1-> L4->L6->L8
U1.AE19: U4.P2	320	6.9	Total Net Delay
A6	272.1	60.1	Vias are L1-> L8->L3->L8
U1.AD19: U4.P8	332	2.2	Total Net Delay
A7	268.9	53.1	Vias are L1-> L4->L6->L8
U1.AD20: U4.R2	322		Total Net Delay
A8	266.4	57.3	Vias are L1-> L8->L3->L8
U1.AE20: U4.R8	323	3.7	Total Net Delay
A9	295.2	39.0	Vias are L1-> L4->L3->L8
U1.AB15: U4.R7	334	4.2	Total Net Delay
A10	259.7	62.5	Vias are L1-> L4->L6->L8
U1.AE6: U4.M3	322	2.2	Total Net Delay
A11	257.4	76.0	Vias are L1-> L8->L3->L8
U1.AE16: U4.T8	333	3.4	Total Net Delay
A12	262.3	52.8	Vias are L1-> L8->L3->L8
U1.AD17: U4.M7	31	5.1	Total Net Delay
A13	303.4	50.6	Vias are L1-> L4->L6->L8
U1.AC7: U4.T2	354		Total Net Delay
BA0	263.1	53.0	Vias are L1-> L4->L3->L8
U1.AE7: U4.N8	310		Total Net Delay
BA1	273.3	42.3	Vias are L1-> L4->L6->L8
U1.AB12: U4.N2	31		Total Net Delay
BG0	271.9	43.7	Vias are L1-> L4->L3->L8

U1.AD14: U4.M2	315	.6	Total Net Delay
CAS_N	298.5	50.5	Vias are L1-> L4->L3->L8
U1.AE9: U4.M8	349	.0	Total Net Delay
CKE0	278.0	36.8	Vias are L1-> L8->L3->L1
U1.AC16: U2.K2	314	.8	Total Net Delay
CKE1	263.9	51.0	Vias are L1-> L8->L6->L8
U1.AE17: U4.K2	314	.9	Total Net Delay
CLK0_C	292.5	40.8	Vias are L1-> L6->L1
U1.AD15: U2.K8	333	.3	Total Net Delay
CLK0_T	293.5	39.6	Vias are L1-> L6->L1
U1.AE15: U2.K7	333	.1	Total Net Delay
CLK1_C	287.9	46.1	Vias are L1-> L3->L8
U1.AE10: U4.K8	334	.0	Total Net Delay
CLK1_T	290.4	43.2	Vias are L1-> L3->L8
U1.AD10: U4.K7	333	.6	Total Net Delay
CS0_N	265.2	47.6	Vias are L1-> L8->L6->L1
U1.AE18: U2.L7	320	).	Total Net Delay
CS1_N	270.6	47.6	Vias are L1-> L4->L3->L8
U1.AC11: U4.L7	318	.2	Total Net Delay
ODT0	277.2	37.3	Vias are L1-> L8->L3->L1
U1.AC12: U2.K3	314	.5	Total Net Delay
ODT1	267.0	47.3	Vias are L1-> L8->L6->L8
U1.AE11: U4.K3	314	.3	Total Net Delay
PAR	297.4	35.0	Vias are L1-> L4->L6->L8
U1.AA12 U4.T3	332	.4	Total Net Delay
RAS_N	273.8	41.8	Vias are L1-> L4->L6->L8
U1.AB10: U4.L8	315	.6	Total Net Delay
WE_N	271.7	48.1	Vias are L1-> L8->L3->L8
U1.AC10: U4.L2	319	.8	Total Net Delay

#### Table 23. DDR4 delay matching example (CA/CTL/CMD/CK signals)

Net Name	PCB Delay (ps)	Pkg Delay (ps)	Comment
DM0	173.9	66.7	Vias are L1-> L6->L8
U1.AD23: U4.E7	240	0.6	Total Net Delay
DQS0_C	172.8	74.9	Vias are L1-> L6->L8
U1.AC25: U4.F3	247	7.7	Total Net Delay
DQS0_T	173.6	73.6	Vias are L1-> L6->L8
U1.AC24: U4.G3	247	7.2	Total Net Delay
DQ0	186.1	69.8	Vias are L1-> L6->L8
U1.AE23: U4.G2	255	5.9	Total Net Delay
DQ1	178.8	73.8	Vias are L1-> L6->L8
U1.AD24: U4.H3	252	2.6	Total Net Delay
DQ2	180.7	59.3	Vias are L1-> L6->L8
U1.AE22: U4.H7	24	10	Total Net Delay
DQ3	173.0	65.0	Vias are L1-> L6->L8
U1.AD22: U4.F7	238		Total Net Delay
DQ4	173.4	73.5	Vias are L1-> L6->L8
U1.AA24: U4.J7	240	6.9	Total Net Delay
DQ5	181.6	72.5	Vias are L1-> L6->L8
U1.Y25: U4.H8	254		Total Net Delay
DQ6	176.2	67.1	Vias are L1-> L6->L8
U1.AA25: U4.H2	243.3		Total Net Delay
DQ7	174.1	68.7	Vias are L1-> L6->L8
U1.AB25: U4.J3	242	2.8	Total Net Delay

### 3.4.3.2. DDR4-2400 Routing Example (i.MX 8MDQLQ)

**Figure 9** to **Figure 13** show the placement and routing of the DDR4 signals on the i.MX 8MDQLQ validation board.

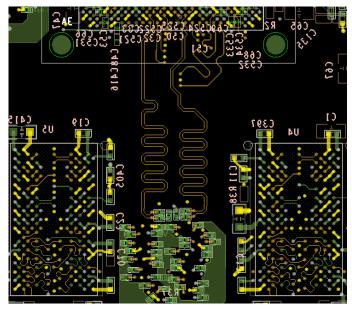


Figure 9. i.MX 8MDQLQ validation board DDR4 routing (top layer)

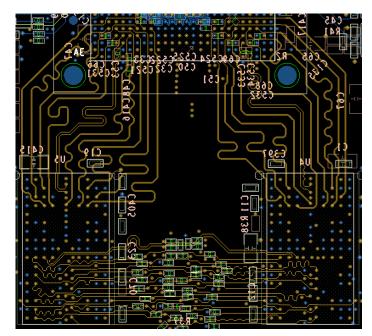


Figure 10. i.MX 8MDQLQ validation board DDR4 routing (Layer 3)

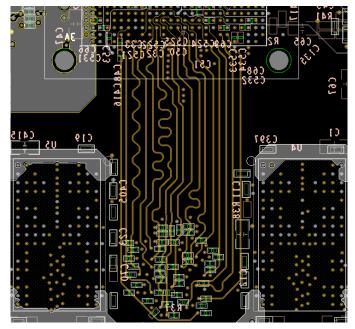


Figure 11. i.MX 8MDQLQ validation board DDR4 routing (Layer 4)

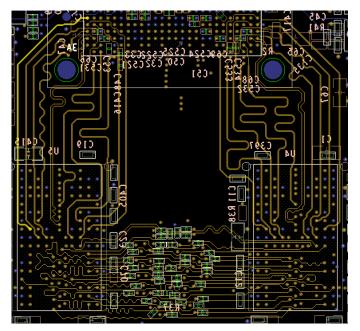


Figure 12. i.MX 8MDQLQ validation board DDR4 routing (Layer 6)

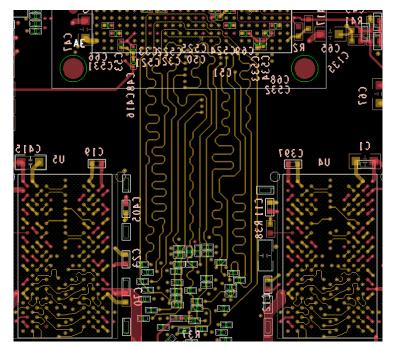


Figure 13. i.MX 8MDQLQ validation board DDR4 routing (Layer 8)

### 3.4.3.3. DDR3L-1600 routing example (i.MX 8MDQLQ)

**Figure 14** to **Figure 18** show the placement and routing of the DDR3L signals on the i.MX 8MDQLQ validation board.

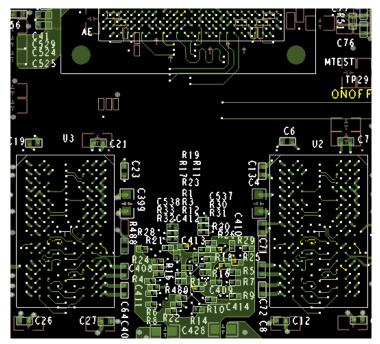


Figure 14. i.MX 8MDQLQ validation board DDR3L routing (top layer)

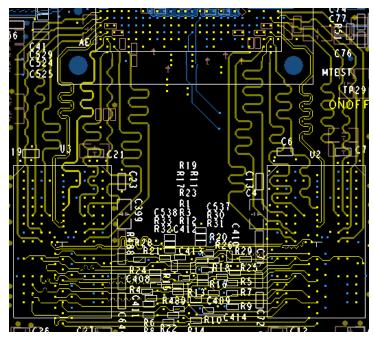


Figure 15. i.MX 8MDQLQ validation board DDR3L routing (Layer 3)

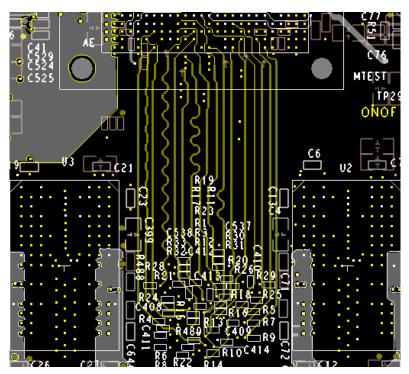


Figure 16. i.MX 8MDQLQ validation board DDR3L routing (Layer 4)

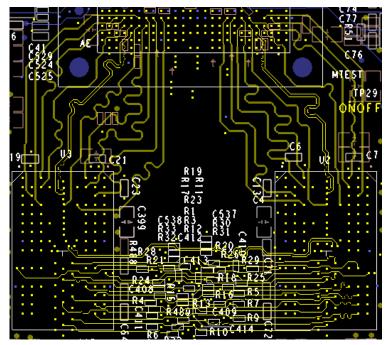


Figure 17. i.MX 8MDQLQ validation board DDR3L routing (Layer 6)

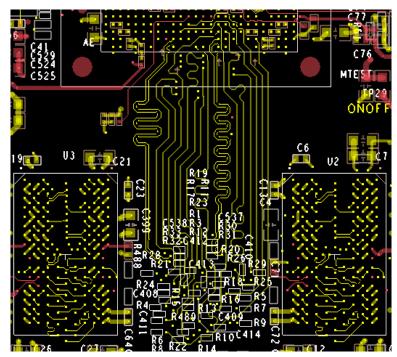


Figure 18. i.MX 8MDQLQ validation board DDR3L routing (Layer 8)

#### 3.4.3.4. DDR4-2400/DDR3L-1600 SI simulation guide

The simulation architecture includes the DDR controller (i.e. the i.MX 8MDQLQ processor), the PCB and the DDR4/DDR3L device. The IBIS model for the i.MX 8MDQLQ processor is available from NXP. The DDR4/DDR3L device IBIS model must be obtained from the memory vendor.

This section introduces how to check SI performance of the layout for a DDR4-2400 /DDR3L-1600 design using the i.MX 8MDQLQ.

- Firstly, perform S-parameter extraction:
  - It requires a 2.5D full-wave extraction tool, such as PowerSI from Cadence.
  - Set the extraction bandwidth to 20 GHz.
  - Port reference impedance: Set 50  $\Omega$  for signal ports and 0.1  $\Omega$  for power ports.
  - Coupled mode: Set rise time to 20 ps and coupling coefficient to 1 %.
- Secondly, perform time domain simulation:
  - Stimulus pattern: 500-bit random code and different pattern for each signal within the same byte.
  - Ideal power.
  - Probe at the die.
  - Simulation at slow corner (worst case).
  - Eye waveform triggered by aligning with the timing reference (DQS/CLK).

#### 3.4.3.5. Eye Width Requirement

The simulated worst eye width should meet following requirement:

- For DDR4-2400
  - DQ Write: Eye width at threshold should be over 260 ps.
  - Add/Cmd: Eye width at threshold should be over 400 ps.
- For DDR3L-1600
  - DQ Write: Eye width at threshold should be over 350 ps.
  - Add/Cmd: Eye width at threshold should be over 600 ps.

Figure 19 shows an example of simulated eye width of DDR4-2400 DQ write.

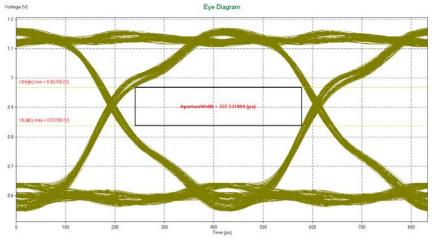


Figure 19. Example of simulated eye width

### 3.4.4. i.MX 8MDQLQ DDR package delay

When performing the required delay matching for LPDDR4/DDR4 routing, the bond wires within the i.MX 8MDQLQ QM package need to be accounted for and included in the match calculation. Table 24 lists the lengths from each die I/O to the package ball, as well as the propagation/fly time from the die I/O to the package ball.

Ball Name	Length (microns)	Delay (ps)	Ball name	Length (microns)	Delay (ps)
DRAM_AC00	5474.2	36.5	DRAM_DM2	10212.9	68.1
DRAM_AC01	7103.5	47.4	DRAM_DM3	6728.3	44.9
DRAM_AC02	7654.0	51.0	DRAM_DQS0_N	10568.8	70.46
DRAM_AC03	7176.6	47.8	DRAM_DQS0_P	10711.6	71.41
DRAM_AC04	6407.3	42.7	DRAM_DQS1_N	6793.6	45.29
DRAM_AC05	6219.0	41.5	DRAM_DQS1_P	6776.4	45.18
DRAM_AC06	6954.1	46.4	DRAM_DQS2_N	10316.5	68.78
DRAM_AC07	6007.4	40.0	DRAM_DQS2_P	10746.9	71.65
DRAM_AC08	7465.4	49.8	DRAM_DQS3_N	7734.3	51.56
DRAM_AC09	11031.9	73.5	DRAM_DQS3_P	7545.1	50.30
DRAM_AC10	7685.0	51.2	DRAM_DQ00	9879.7	65.9
DRAM_AC11	7893.6	52.6	DRAM_DQ01	11130.7	74.2
DRAM_AC12	8785.9	58.6	DRAM_DQ02	8439.7	56.3
DRAM_AC13	8424.5	56.2	DRAM_DQ03	9321.9	62.1
DRAM_AC14	6785.9	45.2	DRAM_DQ04	11139.5	74.3
DRAM_AC15	7189.7	47.9	DRAM_DQ05	10920.2	72.8
DRAM_AC16	6559.5	43.7	DRAM_DQ06	9849.4	65.7
DRAM_AC17	6452.7	43.0	DRAM_DQ07	9805.5	65.4
DRAM_AC19	5633.1	37.6	DRAM_DQ08	6626.6	44.2
DRAM_AC20	6609.6	44.1	DRAM_DQ09	6975.4	46.5
DRAM_AC21	6681.6	44.5	DRAM_DQ10	8074.3	53.8
DRAM_AC22	8329.9	55.5	DRAM_DQ11	6518.8	43.5
DRAM_AC23	8004.5	53.4	DRAM_DQ12	6734.6	44.9
DRAM_AC24	6129.2	40.9	DRAM_DQ13	6746.1	45.0
DRAM_AC25	6594.4	44.0	DRAM_DQ14	5300.8	35.3
DRAM_AC26	5941.5	39.6	DRAM_DQ15	6053.7	40.4
DRAM_AC27	4994.3	33.3	DRAM_DQ16	9074.1	60.5
DRAM_AC28	7671.3	51.1	DRAM_DQ17	10708.2	71.4

Table 24. i.MX 8MDQLQ DDR package trace lengths/delays

Ball Name	Length (microns)	Delay (ps)	Ball name	Length (microns)	Delay (ps)
DRAM_AC29	7386.5	49.2	DRAM_DQ18	10055.7	67.0
DRAM_AC30	8720.1	58.1	DRAM_DQ19	9854.4	65.7
DRAM_AC31	9555.6	63.7	DRAM_DQ20	11381.6	75.9
DRAM_AC32	7136.8	47.6	DRAM_DQ21	10925.5	72.8
DRAM_AC33	7525.5	50.2	DRAM_DQ22	10193.4	68.0
DRAM_AC34	7377.9	49.2	DRAM_DQ23	9977.5	66.5
DRAM_AC35	6469.0	43.1	DRAM_DQ24	7588.0	50.6
DRAM_AC36	5730.8	38.2	DRAM_DQ25	7241.9	48.3
DRAM_AC37	6570.7	43.8	DRAM_DQ26	8836.6	58.9
DRAM_AC38	7224.1	48.2	DRAM_DQ27	5774.4	38.5
DRAM_ALERT_N	6065.6	40.4	DRAM_DQ28	5579.5	37.2
DRAM_RESET_N	4480.6	29.9	DRAM_DQ29	6855.0	45.7
DRAM_DM0	10176.3	67.8	DRAM_DQ30	4834.7	32.2
DRAM_DM1	6512.0	43.4	DRAM_DQ31	4239.0	28.3

Table 24. i.MX 8MDQLQ DDR package trace lengths/delays

### 3.4.5. High-speed routing recommendations

The following lists the routing traces for high speed signals. The propagation delay and the impedance control should match to ensure the correct communication with the devices.

- High-speed signals (DDR, PCIe, RGMII, MIPI, etc.) must not cross gaps in the reference plane.
- Avoid creating slots, voids and splits in reference planes. Review via placements to ensure that they don't inadvertently create splits/voids (i.e. space vias out to eliminate this possibility).
- Ensure that ground stitching vias are present within 50 mils from signal layer transition vias on high speed signals when transitioning between different reference ground planes.
- A solid GND plane must be directly under crystals, associated to components and traces.
- Clocks or strobes that are on the same layer need at least 2.5x height from reference plane spacing from adjacent traces to reduce crosstalk.
- All synchronous interfaces should have appropriate bus length matching and relative clock length control.

For SD module interfaces:

- Match data and CMD trace lengths (allowable delta depends on the access rate being used)
- CLK should be longer than the longest signal in the Data/CMD group (+5 mils).

### 3.4.6. Reset architecture/routing

A debounced reset button may be logical connected to EN pin of PMIC and other discrete power supply chips for development purposes. This allows all voltages to be put to their initial default power-on state when depressing the reset button. See **Figure 20** for a diagram example of the reset functionality.

Pressing the reset button causes the supervisor IC at U704 to assert its RESETn output. This will power down the VDD\_SOC\_0V9 and make PMIC\_ON pulled low by PG signal of U705. Since PMIC\_ON serves as the enable signal of PMIC and other discrete power supply chips, all the power supplies except for the SNVS domain will be OFF. The RESETn will keep asserted for 240 ms after the button is released, thus providing enough time for the power supplies to be completely powered down. During

this time, the POR\_B driven by the PMIC will also keep asserted (low). After RESETn is released, the power supplies will start to ramp up in defined sequence. When all the power supplies have reached their operating voltages, POR\_B will be de-asserted, and the CPU may begin booting from reset.

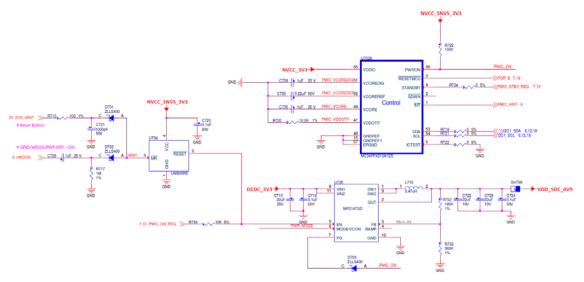


Figure 20. i.MX 8MDQLQ reset routing

### 3.5. Trace impedance recommendations

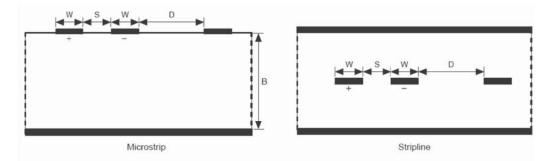
**Table 25** is a reference when you are updating or creating constraints in the PCB design tool to set up the impedances/trace widths.

Signal group	Impedance	PCB manufacturer tolerance (+/-)
LPDDR4 DQ, DMI signals	42 Ω Single-ended	10 %
All single-ended signals, unless specified	50 Ω Single-ended	10 %
DDR DQS/CLK, PCIe TX/RX data pairs	85 Ω Differential	10 %
USB differential signals	90 Ω Differential	10 %
Differential signals, including Ethernet, PCIe clocks, HDMI, MIPI (CSI and DSI)	100 $\Omega$ Differential	10 %

Table 25. Trace impedance recommendations

Figure 21 shows the dimensions of a stripline and microstrip pair. Figure 22 shows the differential pair routing.

- The space between two adjacent differential pairs should be greater than or equal to twice the space between the two individual conductors.
- The skew between HDMI pairs should be within the minimum recommendation ( $\pm 100$  mil).



For better coupling within a differential pair, make S < 2W, S < B, and D = 2S where:

- W = width of a single trace in a differential pair
- S = space between two traces of a differential pair
- D = space between two adjacent differential pairs
- B = thickness of the board

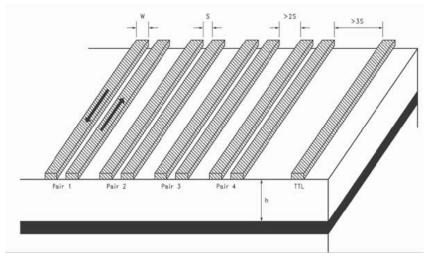


Figure 21. Microstrip and stripline differential pair dimensions

Figure 22. Differential pair routing

### 3.6. Power connectivity/routing

Delivering clean, reliable power to the i.MX 8MDQLQ internal power rails is critical to a successful board design. The PCB PDN should be designed to accommodate the maximum output current from each SMPS into the i.MX 8MDQLQ supply balls. **Table 26** lists the design goals for each high-current i.MX 8MDQLQ power rail.

Table 26. i.MX 8MDQ	LQ maximum	current de	sign levels
---------------------	------------	------------	-------------

Supply input	i.MX 8MDQLQ Max current
VDD_ARM	4A
VDD_SOC	3.6A
VDD_GPU	2A
VDD_VPU	1A
VDD_DRAM	2.5A
NVCC_DRAM	1A

## 3.6.1. i.MX 8MDQLQ power distribution block diagram

There are companion PMICs that provide a low-cost and efficient solution for powering the i.MX 8MDQLQ processor.

**Figure 23** shows a block diagram of the power tree of the NXP i.MX 8MDQLQ EVK board. It uses a single PF4210 PMIC with several discrete buck converters to power ON rails of the processor.

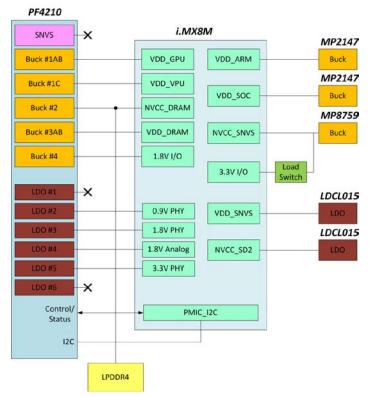


Figure 23. i.MX 8MDQLQ development platform power distribution block diagram

### 3.6.2. Power routing/distribution requirements

The designing for a good Power Delivery Network (PDN) is complicated. It includes:

- 1. Choose a good PCB stackup (adequate Cu thicknesses, and layer assignments/utilization).
- 2. Optimize the placement and routing of the PDN. This includes good placement of the decoupling capacitors and connecting them to the power ground planes with as short and wide a trace as possible (as the increased inductance of a longer etch will degrade the effectivity of the capacitor). Use the number/placement of capacitors on the NXP development platforms.
- 3. Optimize DC IR drop. This involves using very wide traces/plane fills to route high-current power nets and ensure an adequate number of vias on power net layer transitions. Neck down of fill areas should be minimized and current density minimized. The maximum DC IR drop on a board should be 2 % (preferably 1 %) of the voltage rail (i.e. on a 1.1V rail, the maximum voltage drop should be less than 0.022 V, preferably less than 0.011 V). See **Table 27** for the DC IR drop requirement.

AC impedance check – the target impedance at different frequencies should be below specified values. See Table 28 for the impedance targets vs. frequency for specified power rail for the i.MX 8MDQLQ PCB design.

Supply input	Nominal voltage (V)	Max current (mA)	IR drop target	Corresponding power path resistance requirement
VDD_ARM	0.9	4000	<2 %	<4.5 mΩ
VDD_SOC	0.9	3600	<2 %	<7.2 mΩ
VDD_GPU	0.9	2000	<2 %	<9 mΩ
VDD_VPU	0.9	1000	<2 %	<5 mΩ
VDD_DRAM	0.9	2500	<2 %	<18 mΩ
NVCC_DRAM	1.1	1000	<2 %	<22 mΩ

Table 27. i.MX 8MDQLQ DC IR drop requirements

#### Table 28. i.MX 8MDQLQ PDN impedance requirements

Supply Input	< 20 MHz (mΩ)	20 - 100 MHz (mΩ)
VDD_ARM	13.5	63
VDD_SOC	12	50
VDD_GPU	20	90
VDD_VPU	40	150
VDD_DRAM	15	50
NVCC_DRAM	7	30

# 3.7. USB connectivity

The i.MX 8MDQLQ provides two complete USB3.0 interfaces and the following configurations (or any subset) are supported:

- Dedicated host or device using Type-A connector or Type-B connector;
- Dual role using Type-C connector.

To implement a USB Type-C interface (UFP, DFP, or DRP), external hardware must be added to manage the two configuration channel IOs (CC1 and CC2) as well as monitor the plug orientation and switch the single USB3 SS interface.

See the NXP development platform schematic for an example USB Type-C implementation.

### 3.7.1. USB routing recommendations

Use the following recommendations when routing USB signals:

- Route the DP/DM and SS\_TX/SS\_RX differential pairs first.
- Route DP/DM and SS\_TX/SS\_RX signals on the top or bottom layer of the board if possible:
  - Keep DP/DM and SS\_TX/SS\_RX traces as short as possible.
  - Route DP/DM and SS\_TX/SS\_RX signals with a minimum number of corners. Use 45° turns instead of 90° turns.

- Minimize the number of vias on DP/DM and SS\_TX/SS\_RX signals. Do not create stubs or branches.
- The trace width and spacing of the DP/DM and SS\_TX/SS\_RX signals should meet the differential impedance requirement of 90  $\Omega$ .
- Route traces over continuous planes (power and ground).
  - They should not pass over any power/GND plane slots or anti-etch.
- When placing connectors, make sure the ground plane clearouts around each through hole pin have ground continuity between all pins.
- Maintain symmetric routing for each differential pair. Keep the delay skew between P and N less than 1 ps.
- Do not route DP/DM and SS\_TX/SS\_RX traces under oscillators or parallel to clock traces and/or data buses.
- Minimize the lengths of high speed signals that run parallel to the DP/DM and SS\_TX/SS\_RX pairs.
- Provide ground return vias within 50 mils distance from signal layer-transition vias when transitioning between different reference ground planes.

# 3.8. HDMI port connectivity (i.MX 8MDQLQ)

The i.MX 8MDQLQ provides an HDMI transmitter capable of supporting an HDMI2.0 compatible output.

**Figure 24** shows the HDMI connectivity. For the HDMI output,  $604 \Omega$  resistors on the positive and negative sides of each high-speed output pair are grounded through a FET. The gate to this FET should be tied to the 1.8 V power for the HDMI transmit circuitry (HDMI\_AVDDIO, ball P2). This will disconnect the resistors automatically when the HDMI transmit circuitry is powered down. Although a single FET is adequate to achieve the functionality, a dedicated FET for each signal can provide better isolation between signals and minimize crosstalk.

When configured as HDMI output, the two pins named HDMI\_REFCLK\_P and HDMI\_REFCLK\_N are not clock output to the connector. They are input pins to provide 27 MHz reference clock to the HDMI PHY to improve jitter performance. The reference clock is generated by an external oscillator supporting HCSL compatible output. **Table 29** lists the specifications of the reference clock.

Normative electrical		Specificatio	n	Unit	Conditions
parameter	Min.	Тур.	Max.		
External clock frequency	-	27	1	MHz	-
Input duty	45	-	55	%	-
Differential peak-to-peak amplitude at pin	0.5	-	2.2	V	-
Rise/Fall time (10–90 %)	-	-	200	ps	-
Input random jitter	-	-	-140	dBC/Hz	Noise floor density from 10 KHz to 10 MHz.
	-	-	2.963	ps	For a 27 MHz reference, integrated

Table 29. HDMI external reference clock specification
---

					jitter from 10 KHz to 10 MHz.
Input determines tic jitter	-	-	9	ps	Over a band of 10 KHz to 10 MHz

The true HDMI clock output pins are HDMI\_TX\_P\_LN\_3 and HDMI\_TX\_M\_LN\_3. They are connected to the HDMI connector, as shown in **Figure 24**.

Figure 24 does not show optional circuitry (i.e. common mode chokes).

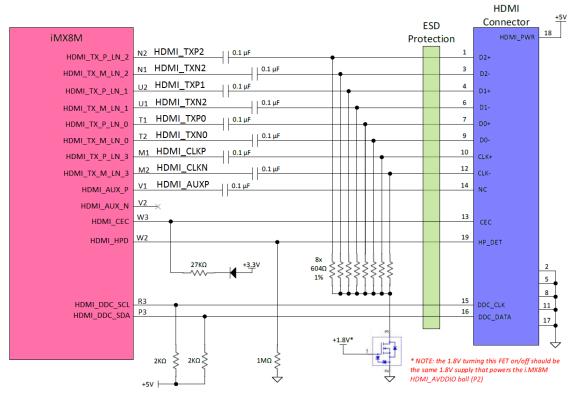


Figure 24. HDMI output connectivity

When planning the HDMI interface, place the 604  $\Omega$  pull-down resistors directly on the signal trace, as shown in **Figure 25**.

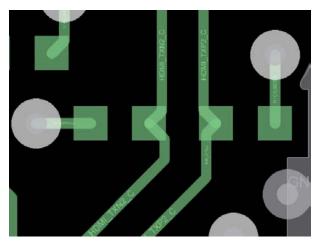


Figure 25. HDMI interface pull-down resistor placement

### 3.9. PCIE connectivity

The i.MX 8MDQLQ has two PCIE interfaces. Each has a pair of pins with the name of PCIEx\_REF\_PAD\_CLK\_P/N. The pins are used to feed 100 MHz reference clock to the PHY from external clock source. They are input-only pins and have no capability to output clock. Do not connect them to PCIE connector or PCIE device.

A PCIE clock generator chip (i.e. 9FGV0241) is used to feed high quality clock to both the PHY and connecter/device. If a PCIE clock generator is not available, use the internal clock of the chip as the clock source of the PHY. The internal clock can be output from CLK2\_P/N (ball T22 and U22) to provide clock to the connector/device. The internal clock exhibits larger jitter than that from PCIE clock generator.

# 3.10. Unused input/output terminations

### 3.10.1. i.MX 8MDQLQ unused input/output guidance

For the i.MX 8MDQLQ, the I/Os and power rails of an unused function can be terminated to reduce overall board power. **Table 30** lists connectivity examples for unused power supply rails and **Table 31** list connectivity examples for unused signal contacts/interfaces.

	· · · ·	
Function	Ball name	Recommendation if unused
MIPI-CSI & MIPI-DSI	MIPI_VDDHA, MIPI_VDDA, MIPI_VDD, MIPI_VDDPLL	Tie to the ground
PCle	PCIE_VPH, PCIE_VPTX, PCIE_VP	Leave unconnected <sup>1</sup>
USB1	USB1_VDD33, USB1_VPH, USB1_VPTX, USB1_VP, USB1_DVDD	Leave unconnected
USB2	USB2_VDD33, USB2_VPH, USB2_VPTX, USB2_VP, USB2_DVDD	Leave unconnected
HDMI	HDMI_AVDDIO, HDMI_AVDDCLK, HDMI_AVDDCORE	Tie to the ground
VPU	VDD_VPU	Leave unconnected
GPU	VDD_GPU	Leave unconnected

Table 30. i.MX 8MDQLQ unused power rail strapping recommendations

Function	Ball name	Recommendation if unused
Digital I/O supplies	NVCC_NAND, NVCC_SAI1, NVCC_SAI2, NVCC_SAI3, NVCC_SAI5, NVCC_GPIO1, NVCC_I2C, NVCC_UART, NVCC_ECSPI, NVCC_SD1, NVCC_SD2, NVDD_ENET	These digital I/O supplies can be left unconnected when the associated I/O balls are not in use CAUTION: Driving/connecting associated I/O balls is prohibited when the power supply is OFF.

Table 30. i.MX 8MDQLQ unu	sed power rail strappin	g recommendations
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Cle interfaces (PCIe1, PCIe2) and must be connected/powered if any PCIe port is used.

Function	Ball name	Recommendation if unused	
MIPI-CSI	MIPI_CSIx_CLK_P/N, MIPI_CSIx_Dx_P/N	Tie to the ground	
MIPI-DSI	MIPI_DSI_CLK_P/N, MIPI_DSI_Dx_P/N	Leave unconnected	
MIPI-DSI	MIPI_DSI_REXT	Tie to the ground	
PCle1	PCIE1_TXN_P/N, PCIE1_REF_PAD_CLK_P/N, PCIE1_RESREF	Leave unconnected	
PCle2	PCIE2_TXN_P/N, PCIE2_REF_PAD_CLK_P/N, PCIE2_RESREF	Leave unconnected	
USB1	USB1_VBUS, USB1_DN/DP, USB1_ID, USB1_TX_P/N, USB1_RX_P/N, USB1_RESREF	Leave unconnected	
USB2	USB2_VBUS, USB2_DN/DP, USB2_ID, USB2_TX_P/N, USB2_RX_P/N, USB2_RESREF	Leave unconnected	
HDMI	HDMI_DDC_SCL, HDMI_DDC_SDA, HDMI_HPD, HDMI_CEC, HDMI_REFCLK_P/N, HDMI_TX_P/M_LN_x, HDMI_AUX_P/N	Leave unconnected	
	HDMI_REXT	Tie to the ground	

Table 31. i.MX 8MDQLQ unused signal strapping recommendations

# 4. Avoiding board bring-up problems

### 4.1. Introduction

This chapter introduces how to avoid mistakes when bringing up a board for the first time. The recommendations below consist of basic techniques for detecting board issues and preventing/locating the three issues encountered: power, clocks, and reset.

## 4.2. Avoiding power pitfalls -Current

Excessive current can damage the board. Use a current-limiting laboratory supply set to the expected main current draw (at most). Monitor the main supply current with an ammeter when powering up the board for the first time. You can use the supply's internal ammeter if there is. By monitoring the main supply current and controlling the current limit, any excessive current can be detected before permanent damage occurs.

Before the board test, you can ohm out the board power rails to the ground to verify that there are no short circuits. Then, you can power on the board and there will not be any damage to the board and/or components.

# 4.3. Avoiding power pitfall -Voltage

To avoid incorrect voltage rails, create a basic table called a voltage report prior to board bring up/testing. The table helps to validate that all the supplies are reaching the expected levels.

To create a voltage report, list the following:

- Board voltage sources
- Default power-up values for the board voltage sources
- Best location on the board to measure the voltage level of each supply

Determine the best measurement location for each power supply to avoid a large voltage drop (IR drop) on the board. The drop causes inaccurate voltage values. The following guidelines help produce the best voltage measurements:

- Measure closest to the load (in the case of the i.MX 8MDQLQ processor).
- Make two measurements: the first after initial board power-up and the second while running a heavy use-case that stresses the i.MX 8MDQLQ processor.

Ensure that the i.MX 8MDQLQ power supply meets the DC electrical specifications as listed in the chip-specific data sheet. See **Table 32** for a sample voltage report table.

#### NOTE

This report table is for the i.MX 8MDQLQ EVK board. Sample voltage reports for customer PCBs will be different from this, depending on the Processor and Power Management IC (PMIC) used and the assignment of the PMIC power resources.

Source	Net name	Expected (V)	Measured (V)	Measure point	Comment
DC jack input	VSYS	12	-	C703.1	Main 12V supply for board
MP8759	NVCC_SNVS_3V3	3.3	-	U801.3	-
LDCL015	VDD_SNVS_0V9	0.9	-	U703.5	-
MP2147	VDD_SOC_0V9	0.9	-	SH708	-
MP2147	VDD_ARM_0V9	0.9	-	SH709	-
PF4210_SW1AB	VDD_GPU_0V9	0.9	-	SH701	-

Table 32. Sample voltage report table

PF4210_SW1C	VDD VPU 0V9	0.9	-	SH702	-
PF4210_SW3AB	VDD_DRAM_0V9	0.9	-	SH704	-
PF4210_LDO4	VDDA_1V8	1.8	-	C754.1	-
IRLML6401	NVCC_3V3	3.3	-	C915.1	-
PF4210_SW4	NVCC_1V8	1.8	-	SH706	-
PF4210_SW2	NVCC_DRAM_1V1	1.1	-	SH703	-
LDCL015	NVCC_SD2	1.8/3.3	-	U1601.5	Can be either under SW control
PF4210_LDO3	VDD_PHY_1V8	1.8	-	C751.1	-
PF4210_LDO2	VDD_PHY_0V9	0.9	-	C749.1	-
PF4210_LDO5	VDD_PHY_3V3	3.3	-	C757.1	-

# 4.4. Checking for clock pitfalls

Problems with the external clocks are another board bring-up issue. Ensure that all the clock sources are running as expected.

The XTALI\_25M/XTALO\_25M, XTALI\_27M/XTALO\_27M and the RTC clocks are the main clock sources for 25 MHz, 27 MHz and 32.768 kHz reference clocks. Although not required, the use of low jitter external oscillators to feed CLK1\_P/N can be an advantage if low jitter or special frequency clock sources are required by modules driven by CLK1\_P/N or CLK2\_P/N. See the CCM chapter in the i.MX 8MDQLQ chip reference manual for details.

When checking crystal frequencies, use an active probe to avoid excessive loading. A passive probe inhibits the 25 MHz and 27 MHz oscillators from starting up. Use the following guidelines:

- RTC clock is running at 32.768 kHz.
- XTALI\_25M/XTALO\_25M is running at 25 MHz (used for the PLL reference).
- XTALI\_27M /XTALO\_27M is running at 27 MHz (used for the PLL reference).

## 4.5. Avoiding reset pitfalls

Follow these guidelines to ensure that you are booting correctly.

- During initial power-on while asserting the POR\_B reset signal, ensure that 25 MHz and 27 MHz clock is active before releasing POR\_B.
- Follow the recommended power-up sequence specified in the i.MX 8MDQLQ data sheet.
- Ensure the POR\_B signal remains asserted (low) until all voltage rails associated with bootup are ON.

The SAI\_TXD[0:7], SAI\_RXD[0:7], BOOT\_MODE[0:1] balls and internal fuses control boot. For a more detailed description about the boot modes, see the system boot chapter in the chip reference manual.

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# 4.6. Sample board bring-up checklist

The checklist incorporates the recommendations described in the previous sections. Blank cells should be filled in during the bring-up.

Checklist item Details		Owner	Findings &Status				
Note: The following items must be completed serially.							
1. Perform a visual inspection	Check major components to make sure nothing has been misplaced or rotated before powering ON.						
2. Verify all i.MX 8MDQLQ voltage rails	Confirm that the voltages match the data sheet's requirements. Be sure to check voltages as close to the i.MX 8MDQLQ as possible (like on a bypass capacitor). This reveals any IR drops on the board that could cause issues later. Ideally, all the i.MX 8MDQLQ voltage rails should be checked, but see guidance below for important rails to check for the i.MX 8MDQLQ. VDD_SNVS, NVC_SNVS, VDD_SOC, VDD_ARM, VDD_DRAM, NVCC_DRAM are particularly important voltages, and must fall within the parameters provided in the i.MX 8MDQLQ data sheet.						
3. Verify power-up sequence	Verify that power on reset (POR_B) is deserted (high) after all power rails have come up and are stable. See the i.MX 8MDQLQ data sheet for details about power-up sequencing.						
4. Measure/probe input clocks (32.768 kHz, 25 MHz, others)	Without proper clocks, the i.MX 8MDQLQ will not function correctly.						
5. Check JTAG connectivity	This is one of the most fundamental and basic access points to the i.MX 8MDQLQ to allow the debug and execution of low level code, and probe/access processor memory.						
Note: The following items may be	worked on in parallel with other bring-up tasks.	-					
Access internal RAM	Verify basic operation of the i.MX 8MDQLQ in system. The on-chip internal RAM starts at address 0x0090 0000 and is 128 Kbytes in density. Perform a basic test by performing a write-read-verify operation to the internal RAM. No software initialization is required to access internal RAM.						
Verify CLKO outputs (measure and verify default clock frequencies for desired clock output options) if the board design supports the probing of clock output balls. Measure boot mode frequencies. Set the boot configure switch for each boot mode and measure the following (depending on system availability): • NAND (probe CE to verify boot, measure RE frequency) • SPI-NOR (probe slave select and measure clock frequency) • MMC/SD (measure clock frequency)	This ensures that the corresponding clock is working and that the PLLs are working. This step requires chip initialization, for example, via the JTAG debugger, to properly set up the IOMUX to output clocks to I/O balls and to set up the clock control module to output the desired clock. See the chip reference manual for more details. This verifies the connectivity of signals between the i.MX 8MDQLQ and boot device and that the boot mode signals are properly set. See the "System Boot" chapter in the chip reference manual for details for boot mode configurations.						

#### Table 33. Board bring-up checklist

Table 33.	Board	bring-up	checklist
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Checklist item	Details	Owner	Findings &Status
Run basic DDR initialization and test memory	<ol> <li>Assuming the use of a JTAG debugger, run the DDR initialization and open a debugger memory window pointing to the DDR memory map starting address.</li> </ol>		
	2. Try writing a few words and verify if they can be read correctly.		
	3. If not, recheck the DDR initialization sequence and whether the DDR has been correctly soldered onto the board. Users should recheck the schematic to ensure that the DDR memory has been connected to the i.MX 8MDQLQ correctly.		



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